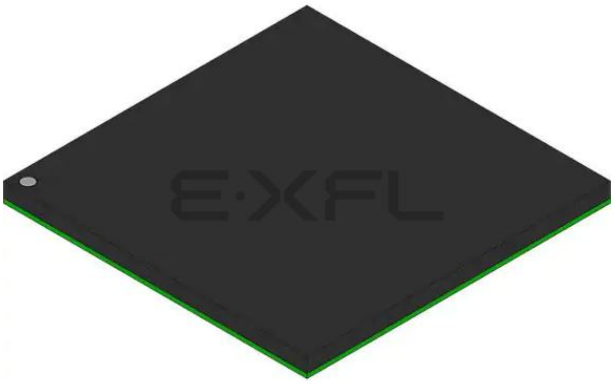


Welcome to E-XFL.COM

Understanding Embedded - Microprocessors

Embedded microprocessors are specialized computing chips designed to perform specific tasks within an embedded system. Unlike general-purpose microprocessors found in personal computers, embedded microprocessors are tailored for dedicated functions within larger systems, offering optimized performance, efficiency, and reliability. These microprocessors are integral to the operation of countless electronic devices, providing the computational power necessary for controlling processes, handling data, and managing communications.

Applications of Embedded - Microprocessors

Embedded microprocessors are utilized across a broad spectrum of applications, making them indispensable in

Details	
Product Status	Active
Core Processor	MPC8xx
Number of Cores/Bus Width	1 Core, 32-Bit
Speed	80MHz
Co-Processors/DSP	Communications; CPM, Security; SEC
RAM Controllers	DRAM
Graphics Acceleration	No
Display & Interface Controllers	-
Ethernet	10Mbps (3), 10/100Mbps (2)
SATA	-
USB	USB 2.0 (1)
Voltage - I/O	3.3V
Operating Temperature	0°C ~ 95°C (TA)
Security Features	Cryptography
Package / Case	357-BBGA
Supplier Device Package	357-PBGA (25x25)
Purchase URL	https://www.e-xfl.com/pro/item?MUrl=&PartUrl=mpc885vr80

1 Overview

The MPC885/MPC880 is a versatile single-chip integrated microprocessor and peripheral combination that can be used in a variety of controller applications and communications and networking systems. The MPC885/MPC880 provides enhanced ATM functionality, an additional fast Ethernet controller, a USB, and an encryption block.

Table 1 shows the functionality supported by MPC885/MPC880.

Table 1. MPC885 Family

Part	Cache (Kbytes)		Ethernet		SCC	SMC	USB	ATM Support	Security Engine
	I Cache	D Cache	10BaseT	10/100					
MPC885	8	8	Up to 3	2	3	2	1	Serial ATM and UTOPIA interface	Yes
MPC880	8	8	Up to 2	2	2	2	1	Serial ATM and UTOPIA interface	No

2 Features

The MPC885/MPC880 is comprised of three modules that each use the 32-bit internal bus: a MPC8xx core, a system integration unit (SIU), and a communications processor module (CPM).

The following list summarizes the key MPC885/MPC880 features:

- Embedded MPC8xx core up to 133 MHz
- Maximum frequency operation of the external bus is 80 MHz (in 1:1 mode)
  - The 133-MHz core frequency supports 2:1 mode only.
  - The 66-/80-MHz core frequencies support both the 1:1 and 2:1 modes.
- Single-issue, 32-bit core (compatible with the Power Architecture definition) with thirty-two 32-bit general-purpose registers (GPRs)
  - The core performs branch prediction with conditional prefetch and without conditional execution.
  - 8-Kbyte data cache and 8-Kbyte instruction cache (see Table 1)
    - Instruction cache is two-way, set-associative with 256 sets in 2 blocks
    - Data cache is two-way, set-associative with 256 sets
    - Cache coherency for both instruction and data caches is maintained on 128-bit (4-word) cache blocks.
    - Caches are physically addressed, implement a least recently used (LRU) replacement algorithm, and are lockable on a cache block basis.
  - MMUs with 32-entry TLB, fully associative instruction and data TLBs
  - MMUs support multiple page sizes of 4, 16, and 512 Kbytes, and 8 Mbytes; 16 virtual address spaces and 16 protection groups
  - Advanced on-chip emulation debug mode

- Provides enhanced ATM functionality found on the MPC862 and MPC866 families and includes the following:
  - — Improved operation, administration and maintenance (OAM) support
  - — OAM performance monitoring (PM) support
  - — Multiple APC priority levels available to support a range of traffic pace requirements
  - — Port-to-port switching capability without the need for RAM-based microcode
  - — Simultaneous MII (100BaseT) and UTOPIA (half- or full -duplex) capability
  - — Optional statistical cell counters per PHY
  - — UTOPIA L2-compliant interface with added FIFO buffering to reduce the total cell transmission time and multi-PHY support. (The earlier UTOPIA L1 specification is also supported.)
  - — Parameter RAM for both SPI and I^2C can be relocated without RAM-based microcode
  - — Supports full-duplex UTOPIA master (ATM side) and slave (PHY side) operations using a split bus
  - — AAL2/VBR functionality is ROM-resident
- Up to 32-bit data bus (dynamic bus sizing for 8, 16, and 32 bits)
- Thirty-two address lines
- Memory controller (eight banks)
  - — Contains complete dynamic RAM (DRAM) controller
  - — Each bank can be a chip select or $\overline{\text{RAS}}$ to support a DRAM bank
  - — Up to 30 wait states programmable per memory bank
  - — Glueless interface to DRAM, SIMMS, SRAM, EPROMs, Flash EPROMs, and other memory devices
  - — DRAM controller programmable to support most size and speed memory interfaces
  - — Four $\overline{\text{CAS}}$ lines, four $\overline{\text{WE}}$ lines, and one $\overline{\text{OE}}$ line
  - — Boot chip-select available at reset (options for 8-, 16-, or 32-bit memory)
  - — Variable block sizes (32 Kbytes–256 Mbytes)
  - — Selectable write protection
  - — On-chip bus arbitration logic
- General-purpose timers
  - — Four 16-bit timers or two 32-bit timers
  - — Gate mode can enable/disable counting.
  - — Interrupt can be masked on reference match and event capture
- Two fast Ethernet controllers (FEC)—Two 10/100 Mbps Ethernet/IEEE Std. 802.3™ CDMA/CS that interface through MII and/or RMII interfaces
- System integration unit (SIU)
  - — Bus monitor
  - — Software watchdog

- On-chip 16 × 16 multiply accumulate controller (MAC)
  - One operation per clock (two-clock latency, one-clock blockage)
  - MAC operates concurrently with other instructions
  - FIR loop—Four clocks per four multiplies
- Four baud rate generators
  - Independent (can be connected to any SCC or SMC)
  - Allow changes during operation
  - Autobaud support option
- Up to three serial communication controllers (SCCs) supporting the following protocols:
  - Serial ATM capability on SCCs
  - Optional UTOPIA port on SCC4
  - Ethernet/IEEE Std 802.3™ optional on the SCC(s) supporting full 10-Mbps operation
  - HDLC/SDLC
  - HDLC bus (implements an HDLC-based local area network (LAN))
  - Asynchronous HDLC to support point-to-point protocol (PPP)
  - AppleTalk
  - Universal asynchronous receiver transmitter (UART)
  - Synchronous UART
  - Serial infrared (IrDA)
  - Binary synchronous communication (BISYNC)
  - Totally transparent (bit streams)
  - Totally transparent (frame based with optional cyclic redundancy check (CRC))
- Up to two serial management channels (SMCs) supporting the following protocols:
  - UART (low-speed operation)
  - Transparent
  - General circuit interface (GCI) controller
  - Provide management for BRI devices as GCI controller in time-division multiplexed (TDM) channels
- Universal serial bus (USB)—Supports operation as a USB function endpoint, a USB host controller, or both for testing purposes (loop-back diagnostics)
  - USB 2.0 full-/low-speed compatible
  - The USB function mode has the following features:
    - Four independent endpoints support control, bulk, interrupt, and isochronous data transfers.
    - CRC16 generation and checking
    - CRC5 checking
    - NRZI encoding/decoding with bit stuffing
    - 12- or 1.5-Mbps data rate

5 Power Dissipation

Table 5 provides information on power dissipation. The modes are 1:1, where CPU and bus speeds are equal, and 2:1, where CPU frequency is twice bus speed.

Table 5. Power Dissipation (P_D)

Die Revision	Bus Mode	CPU Frequency	Typical[1]	Maximum[2]	Unit
0	1:1	66 MHz	310	390	mW
		80 MHz	350	430	mW
	2:1	133 MHz	430	495	mW

[1] Typical power dissipation at V_{DDL} = V_{DDSYN} = 1.8 V, and V_{DDH} is at 3.3 V.
[2] Maximum power dissipation at V_{DDL} = V_{DDSYN} = 1.9 V, and V_{DDH} is at 3.5 V.

NOTE

The values in Table 5 represent V_{DDL}-based power dissipation and do not include I/O power dissipation over V_{DDH}. I/O power dissipation varies widely by application due to buffer current, depending on external circuitry.

The V_{DDSYN} power dissipation is negligible.

6 DC Characteristics

Table 6 provides the DC electrical characteristics for the MPC885/MPC880.

Table 6. DC Electrical Specifications

Characteristic	Symbol	Min	Max	Unit
Operating voltage	V_{DDL} (core)	1.7	1.9	V
	V_{DDH} (I/O)	3.135	3.465	V
	V_{DDSYN}[1]	1.7	1.9	V
	Difference between V_{DDL} and V_{DDSYN}	—	100	mV
Input high voltage (all inputs except EXTAL and EXTCLK)[2]	V_{IH}	2.0	3.465	V
Input low voltage[3]	V_{IL}	GND	0.8	V
EXTAL, EXTCLK input high voltage	V_{IHC}	0.7*(V_{DDH})	V_{DDH}	V
Input leakage current, Vin = 5.5 V (except TMS, $\overline{TRST}$, DSCK and DSDI pins) for 5-V tolerant pins [2]	I_{in}	—	100	µA
Input leakage current, V_{in} = V_{DDH} (except TMS, $\overline{TRST}$, DSCK, and DSDI)	I_{In}	—	10	µA
Input leakage current, V_{in} = 0 V (except TMS, $\overline{TRST}$, DSCK and DSDI pins)	I_{In}	—	10	µA
Input capacitance[4]	C_{in}	—	20	pF

7.6 References

Semiconductor Equipment and Materials International(415) 964-5111
805 East Middlefield Rd
Mountain View, CA 94043

MIL-SPEC and EIA/JESD (JEDEC) specifications800-854-7179 or
(Available from Global Engineering Documents)303-397-7956

JEDEC Specifications http://www.jedec.org

1. C.E. Triplett and B. Joiner, “An Experimental Characterization of a 272 PBGA Within an Automotive Engine Controller Module,” Proceedings of SemiTherm, San Diego, 1998, pp. 47–54.
2. 2. B. Joiner and V. Adams, “Measurement and Simulation of Junction to Board Thermal Resistance and Its Application in Thermal Modeling,” Proceedings of SemiTherm, San Diego, 1999, pp. 212–220.

8 Power Supply and Power Sequencing

This section provides design considerations for the MPC885/MPC880 power supply. The MPC885/MPC880 has a core voltage (V_{DDL}) and PLL voltage (V_{DDSYN}), which both operate at a lower voltage than the I/O voltage V_{DDH}. The I/O section of the MPC885/MPC880 is supplied with 3.3 V across V_{DDH} and V_{SS} (GND).

The signals PA[0:15], PB[14:31], PC[4:15], PD[3:15], TDI, TDO, TCK, TRST_B, TMS, MII_TXEN, and MII_MDIO are 5 V tolerant. All inputs cannot be more than 2.5 V greater than V_{DDH}. In addition, 5-V tolerant pins cannot exceed 5.5 V and remaining input pins cannot exceed 3.465 V. This restriction applies to power up/down and normal operation.

One consequence of multiple power supplies is that when power is initially applied the voltage rails ramp up at different rates. The rates depend on the nature of the power supply, the type of load on each power supply, and the manner in which different voltages are derived. The following restrictions apply:

- V_{DDL} must not exceed V_{DDH} during power up and power down.
- V_{DDL} must not exceed 1.9 V, and V_{DDH} must not exceed 3.465 V.

These cautions are necessary for the long-term reliability of the part. If they are violated, the electrostatic discharge (ESD) protection diodes are forward-biased, and excessive current can flow through these diodes. If the system power supply design does not control the voltage sequencing, the circuit shown Figure 5 can be added to meet these requirements. The MUR420 Schottky diodes control the maximum potential difference between the external bus and core power supplies on power up, and the 1N5820 diodes regulate the maximum potential difference on power down.

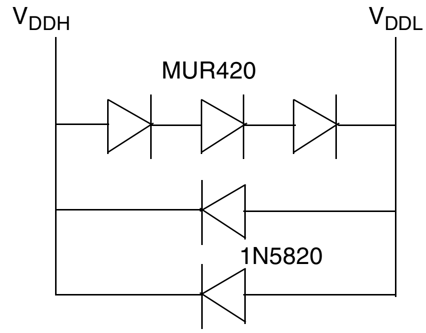


Figure 5. Example Voltage Sequencing Circuit

9 Layout Practices

Each V_{DD} pin on the MPC885/MPC880 should be provided with a low-impedance path to the board's supply. Each GND pin should likewise be provided with a low-impedance path to ground. The power supply pins drive distinct groups of logic on chip. The V_{DD} power supply should be bypassed to ground using at least four 0.1 µF by-pass capacitors located as close as possible to the four sides of the package. Each board designed should be characterized and additional appropriate decoupling capacitors should be used if required. The capacitor leads and associated printed-circuit traces connecting to chip V_{DD} and GND should be kept to less than half an inch per capacitor lead. At a minimum, a four-layer board employing two inner layers as V_{DD} and GND planes should be used.

All output pins on the MPC885/MPC880 have fast rise and fall times. Printed-circuit (PC) trace interconnection length should be minimized in order to minimize undershoot and reflections caused by these fast output switching times. This recommendation particularly applies to the address and data buses. Maximum PC trace lengths of six inches are recommended. Capacitance calculations should consider all device loads as well as parasitic capacitances due to the PC traces. Attention to proper PCB layout and bypassing becomes especially critical in systems with higher capacitive loads because these loads create higher transient currents in the V_{DD} and GND circuits. Pull up all unused inputs or signals that will be inputs during reset. Special care should be taken to minimize the noise levels on the PLL supply pins. For more information, please refer to the *MPC885 PowerQUICC™ Family Reference Manual*, Section 14.4.3, "Clock Synthesizer Power (V_{DDSYN}, V_{SSSYN}, V_{SSSYN1})."

10 Bus Signal Timing

The maximum bus speed supported by the MPC885/MPC880 is 80 MHz. Higher-speed parts must be operated in half-speed bus mode (for example, an MPC885/MPC880 used at 133 MHz must be configured for a 66 MHz bus). Table 7 shows the frequency ranges for standard part frequencies in 1:1 bus mode, and Table 8 shows the frequency ranges for standard part frequencies in 2:1 bus mode.

Table 7. Frequency Ranges for Standard Part Frequencies (1:1 Bus Mode)

Part Frequency	66 MHz		80 MHz	
	Min	Max	Min	Max
Core frequency	40	66.67	40	80
Bus frequency	40	66.67	40	80

Table 8. Frequency Ranges for Standard Part Frequencies (2:1 Bus Mode)

Part Frequency	66 MHz		80 MHz		133 MHz	
	Min	Max	Min	Max	Min	Max
Core frequency	40	66.67	40	80	40	133
Bus frequency	20	33.33	20	40	20	66

Table 9 provides the timings for the MPC885/MPC880 at 33-, 40-, 66-, and 80-MHz bus operation.

The timing for the MPC885/MPC880 bus shown assumes a 50-pF load for maximum delays and a 0-pF load for minimum delays. CLKOUT assumes a 100-pF load for maximum delays and a 50-pF load for minimum delays.

Table 9. Bus Operation Timings

Num	Characteristic	33 MHz		40 MHz		66 MHz		80 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
B1	Bus period (CLKOUT), see Table 7	—	—	—	—	—	—	—	—	ns
B1a	EXTCLK to CLKOUT phase skew - If CLKOUT is an integer multiple of EXTCLK, then the rising edge of EXTCLK is aligned with the rising edge of CLKOUT. For a non-integer multiple of EXTCLK, this synchronization is lost, and the rising edges of EXTCLK and CLKOUT have a continuously varying phase skew.	–2	+2	–2	+2	–2	+2	–2	+2	ns
B1b	CLKOUT frequency jitter peak-to-peak	—	1	—	1	—	1	—	1	ns
B1c	Frequency jitter on EXTCLK	—	0.50	—	0.50	—	0.50	—	0.50	%
B1d	CLKOUT phase jitter peak-to-peak for OSCLK ≥ 15 MHz	—	4	—	4	—	4	—	4	ns
	CLKOUT phase jitter peak-to-peak for OSCLK < 15 MHz	—	5	—	5	—	5	—	5	ns
B2	CLKOUT pulse width low (MIN = 0.4 × B1, MAX = 0.6 × B1)	12.1	18.2	10.0	15.0	6.1	9.1	5.0	7.5	ns
B3	CLKOUT pulse width high (MIN = 0.4 × B1, MAX = 0.6 × B1)	12.1	18.2	10.0	15.0	6.1	9.1	5.0	7.5	ns
B4	CLKOUT rise time	—	4.00	—	4.00	—	4.00	—	4.00	ns

Table 9. Bus Operation Timings (continued)

Num	Characteristic	33 MHz		40 MHz		66 MHz		80 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
B16b	$\overline{BB}$, $\overline{BG}$, $\overline{BR}$, valid to CLKOUT (setup time)[2] (4MIN = 0.00 × B1 + 0.00)	4.00	—	4.00	—	4.00	—	4.00	—	ns
B17	CLKOUT to $\overline{TA}$, $\overline{TEA}$, $\overline{BI}$, $\overline{BB}$, $\overline{BG}$, $\overline{BR}$ valid (hold time) (MIN = 0.00 × B1 + 1.00[3])	1.00	—	1.00	—	2.00	—	2.00	—	ns
B17a	CLKOUT to $\overline{KR}$, $\overline{RETRY}$, $\overline{CR}$ valid (hold time) (MIN = 0.00 × B1 + 2.00)	2.00	—	2.00	—	2.00	—	2.00	—	ns
B18	D(0:31) valid to CLKOUT rising edge (setup time)[4] (MIN = 0.00 × B1 + 6.00)	6.00	—	6.00	—	6.00	—	6.00	—	ns
B19	CLKOUT rising edge to D(0:31) valid (hold time)[4] (MIN = 0.00 × B1 + 1.00[5])	1.00	—	1.00	—	2.00	—	2.00	—	ns
B20	D(0:31) valid to CLKOUT falling edge (setup time)[6] (MIN = 0.00 × B1 + 4.00)	4.00	—	4.00	—	4.00	—	4.00	—	ns
B21	CLKOUT falling edge to D(0:31) valid (hold time)[6] (MIN = 0.00 × B1 + 2.00)	2.00	—	2.00	—	2.00	—	2.00	—	ns
B22	CLKOUT rising edge to $\overline{CS}$ asserted GPCM ACS = 00 (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.43	ns
B22a	CLKOUT falling edge to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = [0 or 1] (MAX = 0.00 × B1 + 8.00)	—	8.00	—	8.00	—	8.00	—	8.00	ns
B22b	CLKOUT falling edge to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = [0 or 1], EBDF = 0 (MAX = 0.25 × B1 + 6.3)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.43	ns
B22c	CLKOUT falling edge to $\overline{CS}$ asserted GPCM ACS = 11, TRLX = [0 or 1], EBDF = 1 (MAX = 0.375 × B1 + 6.6)	10.90	18.00	10.90	16.00	5.20	12.30	4.69	10.93	ns
B23	CLKOUT rising edge to $\overline{CS}$ negated GPCM read access, GPCM write access ACS = 00 and CSNT = 0 (MAX = 0.00 × B1 + 8.00)	2.00	8.00	2.00	8.00	2.00	8.00	2.00	8.00	ns
B24	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 0 (MIN = 0.25 × B1 – 2.00)	5.60	—	4.30	—	1.80	—	1.13	—	ns
B24a	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 11 TRLX = 0 (MIN = 0.50 × B1 – 2.00)	13.20	—	10.50	—	5.60	—	4.25	—	ns
B25	CLKOUT rising edge to $\overline{OE}$, $\overline{WE}$(0:3) asserted (MAX = 0.00 × B1 + 9.00)	—	9.00	—	9.00	—	9.00	—	9.00	ns
B26	CLKOUT rising edge to $\overline{OE}$ negated (MAX = 0.00 × B1 + 9.00)	2.00	9.00	2.00	9.00	2.00	9.00	2.00	9.00	ns
B27	A(0:31) and BADDR(28:30) to $\overline{CS}$ asserted GPCM ACS = 10, TRLX = 1 (MIN = 1.25 × B1 – 2.00)	35.90	—	29.30	—	16.90	—	13.60	—	ns

Table 9. Bus Operation Timings (continued)

Num	Characteristic	33 MHz		40 MHz		66 MHz		80 MHz		Unit
		Min	Max	Min	Max	Min	Max	Min	Max	
B29h	$\overline{WE}$(0:3) negated to D(0:31) High-Z GPCM write access, TRLX = 1, CSNT = 1, EBDF = 1 (MIN = 0.375 × B1 – 3.30)	38.40	—	31.10	—	17.50	—	13.85	—	ns
B29i	$\overline{CS}$ negated to D(0:31) High-Z GPCM write access, TRLX = 1, CSNT = 1, ACS = 10 or ACS = 11, EBDF = 1 (MIN = 0.375 × B1 – 3.30)	38.40	—	31.10	—	17.50	—	13.85	—	ns
B30	$\overline{CS}$, $\overline{WE}$(0:3) negated to A(0:31), BADDR(28:30) Invalid GPCM read/write access[8] (MIN = 0.25 × B1 – 2.00)	5.60	—	4.30	—	1.80	—	1.13	—	ns
B30a	$\overline{WE}$(0:3) negated to A(0:31), BADDR(28:30) Invalid GPCM, write access, TRLX = 0, CSNT = 1, $\overline{CS}$ negated to A(0:31) invalid GPCM write access TRLX = 0, CSNT =1 ACS = 10, or ACS == 11, EBDF = 0 (MIN = 0.50 × B1 – 2.00)	13.20	—	10.50	—	5.60	—	4.25	—	ns
B30b	$\overline{WE}$(0:3) negated to A(0:31) invalid GPCM BADDR(28:30) invalid GPCM write access, TRLX = 1, CSNT = 1. $\overline{CS}$ negated to A(0:31) invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10, or ACS == 11 EBDF = 0 (MIN = 1.50 × B1 – 2.00)	43.50	—	35.50	—	20.70	—	16.75	—	ns
B30c	$\overline{WE}$(0:3) negated to A(0:31), BADDR(28:30) invalid GPCM write access, TRLX = 0, CSNT = 1. $\overline{CS}$ negated to A(0:31) invalid GPCM write access, TRLX = 0, CSNT = 1 ACS = 10, ACS == 11, EBDF = 1 (MIN = 0.375 × B1 – 3.00)	8.40	—	6.40	—	2.70	—	1.70	—	ns
B30d	$\overline{WE}$(0:3) negated to A(0:31), BADDR(28:30) invalid GPCM write access TRLX = 1, CSNT =1, $\overline{CS}$ negated to A(0:31) invalid GPCM write access TRLX = 1, CSNT = 1, ACS = 10 or 11, EBDF = 1	38.67	—	31.38	—	17.83	—	14.19	—	ns
B31	CLKOUT falling edge to $\overline{CS}$ valid, as requested by control bit CST4 in the corresponding word in the UPM (MAX = 0.00 × B1 + 6.00)	1.50	6.00	1.50	6.00	1.50	6.00	1.50	6.00	ns
B31a	CLKOUT falling edge to $\overline{CS}$ valid, as requested by control bit CST1 in the corresponding word in the UPM (MAX = 0.25 × B1 + 6.80)	7.60	14.30	6.30	13.00	3.80	10.50	3.13	10.00	ns
B31b	CLKOUT rising edge to $\overline{CS}$ valid, as requested by control bit CST2 in the corresponding word in the UPM (MAX = 0.00 × B1 + 8.00)	1.50	8.00	1.50	8.00	1.50	8.00	1.50	8.00	ns
B31c	CLKOUT rising edge to $\overline{CS}$ valid, as requested by control bit CST3 in the corresponding word in the UPM (MAX = 0.25 × B1 + 6.30)	7.60	13.80	6.30	12.50	3.80	10.00	3.13	9.40	ns
B31d	CLKOUT falling edge to $\overline{CS}$ valid, as requested by control bit CST1 in the corresponding word in the UPM EBDF = 1 (MAX = 0.375 × B1 + 6.6)	13.30	18.00	11.30	16.00	7.60	12.30	4.69	11.30	ns

Figure 6 provides the control timing diagram.

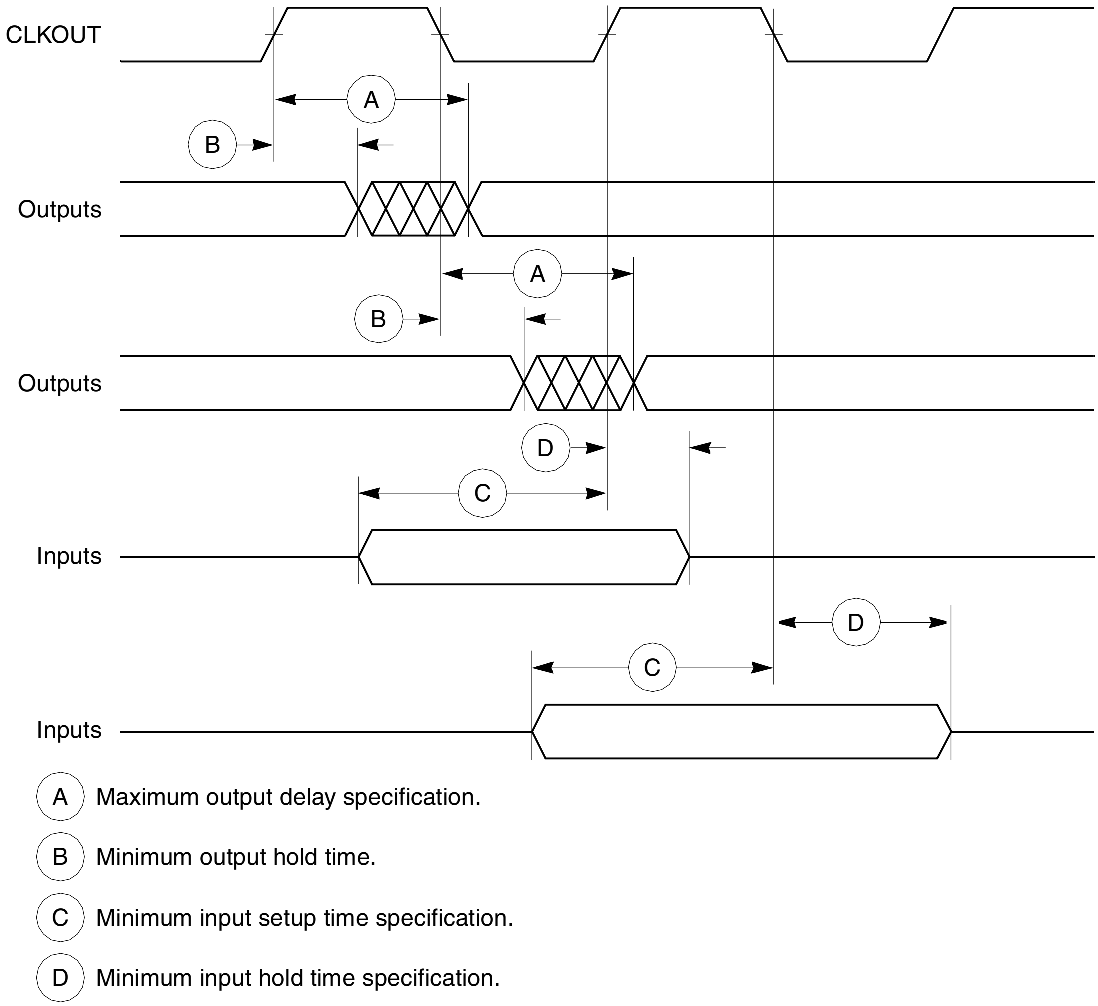


Figure 6. Control Timing

Figure 7 provides the timing for the external clock.

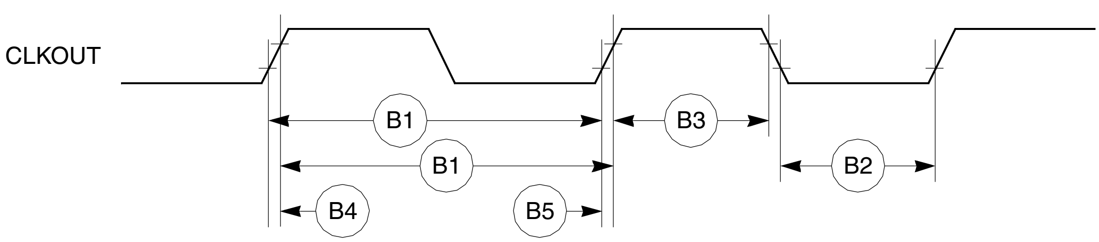


Figure 7. External Clock Timing

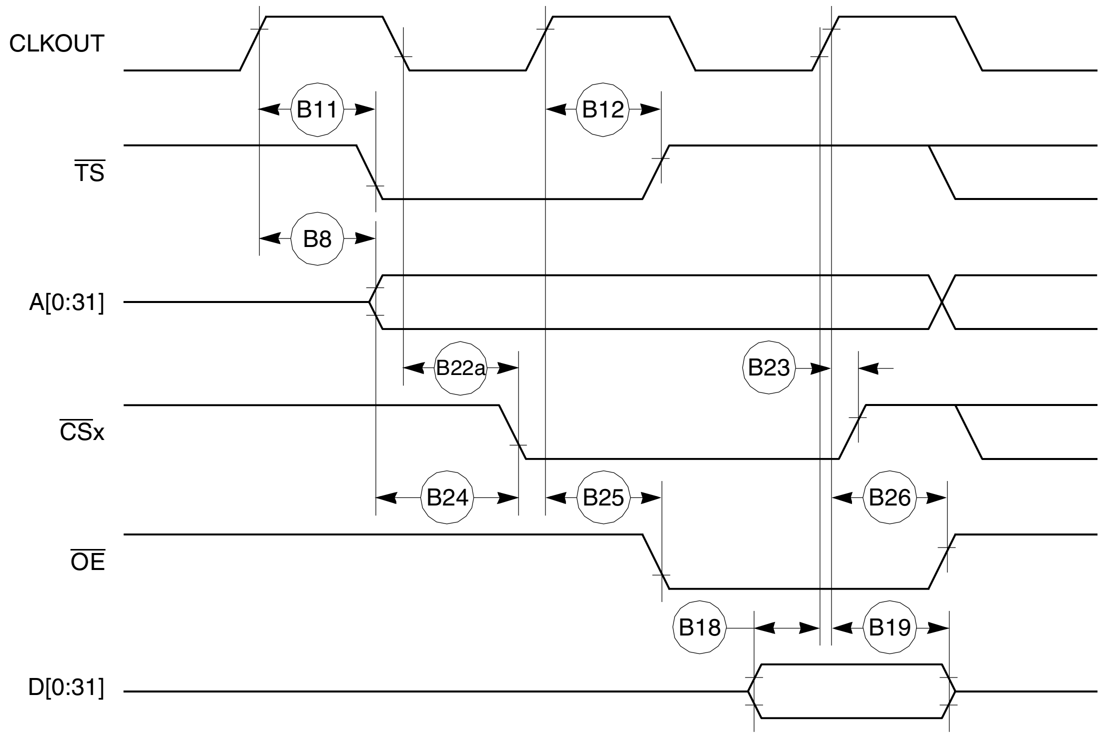


Figure 14. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 10)

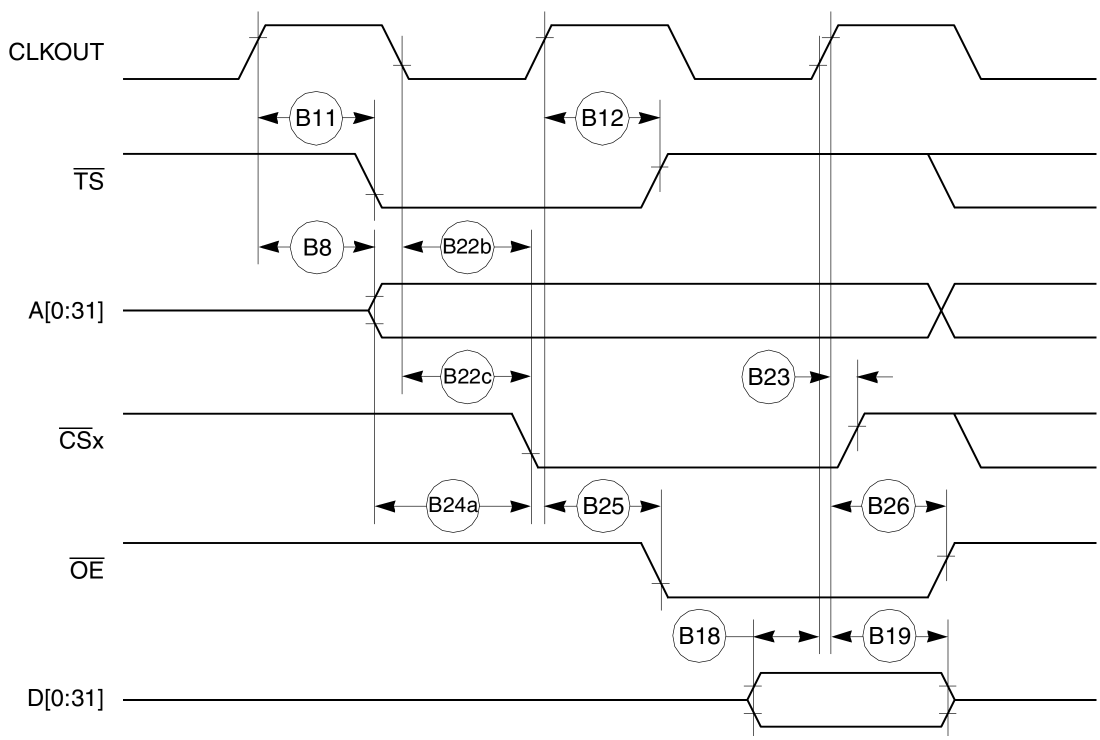


Figure 15. External Bus Read Timing (GPCM Controlled—TRLX = 0, ACS = 11)

12.5 Timer AC Electrical Specifications

Table 20 provides the general-purpose timer timings as shown in Figure 53.

Table 20. Timer Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
61	TIN/$\overline{\text{TGATE}}$ rise and fall time	10	—	ns
62	TIN/$\overline{\text{TGATE}}$ low time	1	—	clk
63	TIN/$\overline{\text{TGATE}}$ high time	2	—	clk
64	TIN/$\overline{\text{TGATE}}$ cycle time	3	—	clk
65	CLKO low to $\overline{\text{TOUT}}$ valid	3	25	ns

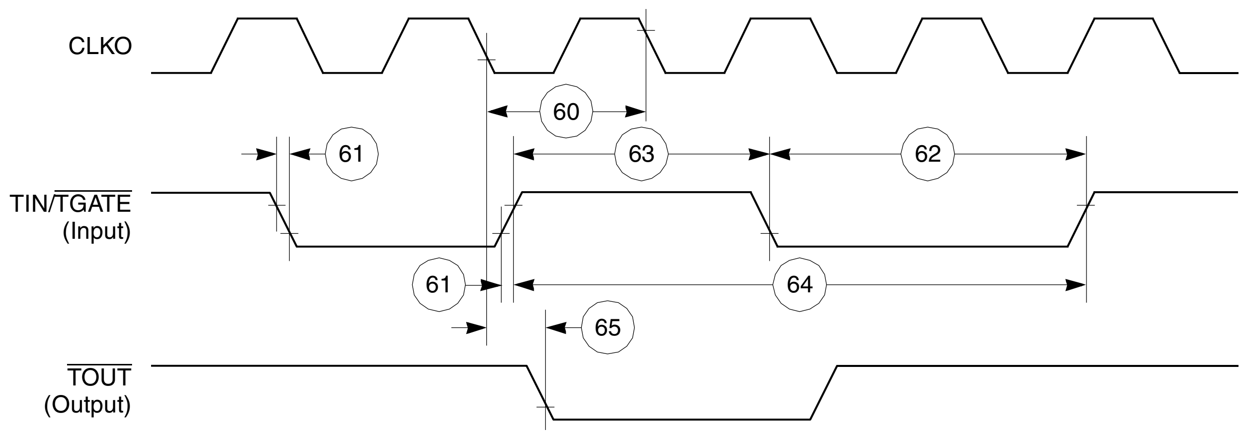


Figure 53. CPM General-Purpose Timers Timing Diagram

12.6 Serial Interface AC Electrical Specifications

Table 21 provides the serial interface timings as shown in Figure 54 through Figure 58.

Table 21. SI Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
70	L1RCLK, L1TCLK frequency (DSC = 0)[1, 2]	—	SYNCCLK/2.5	MHz
71	L1RCLK, L1TCLK width low (DSC = 0)[2]	P + 10	—	ns
71a	L1RCLK, L1TCLK width high (DSC = 0)[3]	P + 10	—	ns
72	L1TXD, L1ST(1–4), $\overline{\text{L1RQ}}$, L1CLKO rise/fall time	—	15.00	ns
73	L1RSYNC, L1TSYNC valid to L1CLK edge (SYNC setup time)	20.00	—	ns
74	L1CLK edge to L1RSYNC, L1TSYNC, invalid (SYNC hold time)	35.00	—	ns
75	L1RSYNC, L1TSYNC rise/fall time	—	15.00	ns

Table 21. SI Timing (continued)

Num	Characteristic	All Frequencies		Unit
		Min	Max	
76	L1RXD valid to L1CLK edge (L1RXD setup time)	17.00	—	ns
77	L1CLK edge to L1RXD invalid (L1RXD hold time)	13.00	—	ns
78	L1CLK edge to L1ST(1–4) valid[4]	10.00	45.00	ns
78A	L1SYNC valid to L1ST(1–4) valid	10.00	45.00	ns
79	L1CLK edge to L1ST(1–4) invalid	10.00	45.00	ns
80	L1CLK edge to L1TXD valid	10.00	55.00	ns
80A	L1TSYNC valid to L1TXD valid[4]	10.00	55.00	ns
81	L1CLK edge to L1TXD high impedance	0.00	42.00	ns
82	L1RCLK, L1TCLK frequency (DSC =1)	—	16.00 or SYNCCLK/2	MHz
83	L1RCLK, L1TCLK width low (DSC =1)	P + 10	—	ns
83a	L1RCLK, L1TCLK width high (DSC = 1)[3]	P + 10	—	ns
84	L1CLK edge to L1CLKO valid (DSC = 1)	—	30.00	ns
85	$\overline{\text{L1RQ}}$ valid before falling edge of L1TSYNC[4]	1.00	—	L1TCLK
86	L1GR setup time[2]	42.00	—	ns
87	L1GR hold time	42.00	—	ns
88	L1CLK edge to L1SYNC valid (FSD = 00) CNT = 0000, BYT = 0, DSC = 0)	—	0.00	ns

1 The ratio SyncCLK/L1RCLK must be greater than 2.5/1.
2 These specs are valid for IDL mode only.
3 Where P = 1/CLKOUT. Thus for a 25-MHz CLKO1 rate, P = 40 ns.
4 These strobes and TxD on the first bit of the frame become valid after L1CLK edge or L1SYNC, whichever comes later.

12.7 SCC in NMSI Mode Electrical Specifications

Table 22 provides the NMSI external clock timing.

Table 22. NMSI External Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
100	RCLK1 and TCLK1 width high[1]	1/SYNCCLK	—	ns
101	RCLK1 and TCLK1 width low	1/SYNCCLK + 5	—	ns
102	RCLK1 and TCLK1 rise/fall time	—	15.00	ns
103	TXD1 active delay (from TCLK1 falling edge)	0.00	50.00	ns
104	$\overline{\text{RTS1}}$ active/inactive delay (from TCLK1 falling edge)	0.00	50.00	ns
105	$\overline{\text{CTS1}}$ setup time to TCLK1 rising edge	5.00	—	ns
106	RXD1 setup time to RCLK1 rising edge	5.00	—	ns
107	RXD1 hold time from RCLK1 rising edge[2]	5.00	—	ns
108	$\overline{\text{CD1}}$ setup time to RCLK1 rising edge	5.00	—	ns

[1] The ratios SyncCLK/RCLK1 and SyncCLK/TCLK1 must be greater than or equal to 2.25/1.
[2] Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as external sync signals.

Table 23 provides the NMSI internal clock timing.

Table 23. NMSI Internal Clock Timing

Num	Characteristic	All Frequencies		Unit
		Min	Max	
100	RCLK1 and TCLK1 frequency[1]	0.00	SYNCCLK/3	MHz
102	RCLK1 and TCLK1 rise/fall time	—	—	ns
103	TXD1 active delay (from TCLK1 falling edge)	0.00	30.00	ns
104	$\overline{\text{RTS1}}$ active/inactive delay (from TCLK1 falling edge)	0.00	30.00	ns
105	$\overline{\text{CTS1}}$ setup time to TCLK1 rising edge	40.00	—	ns
106	RXD1 setup time to RCLK1 rising edge	40.00	—	ns
107	RXD1 hold time from RCLK1 rising edge[2]	0.00	—	ns
108	$\overline{\text{CD1}}$ setup time to RCLK1 rising edge	40.00	—	ns

[1] The ratios SyncCLK/RCLK1 and SyncCLK/TCLK1 must be greater than or equal to 3/1.
[2] Also applies to $\overline{\text{CD}}$ and $\overline{\text{CTS}}$ hold time when they are used as external sync signals

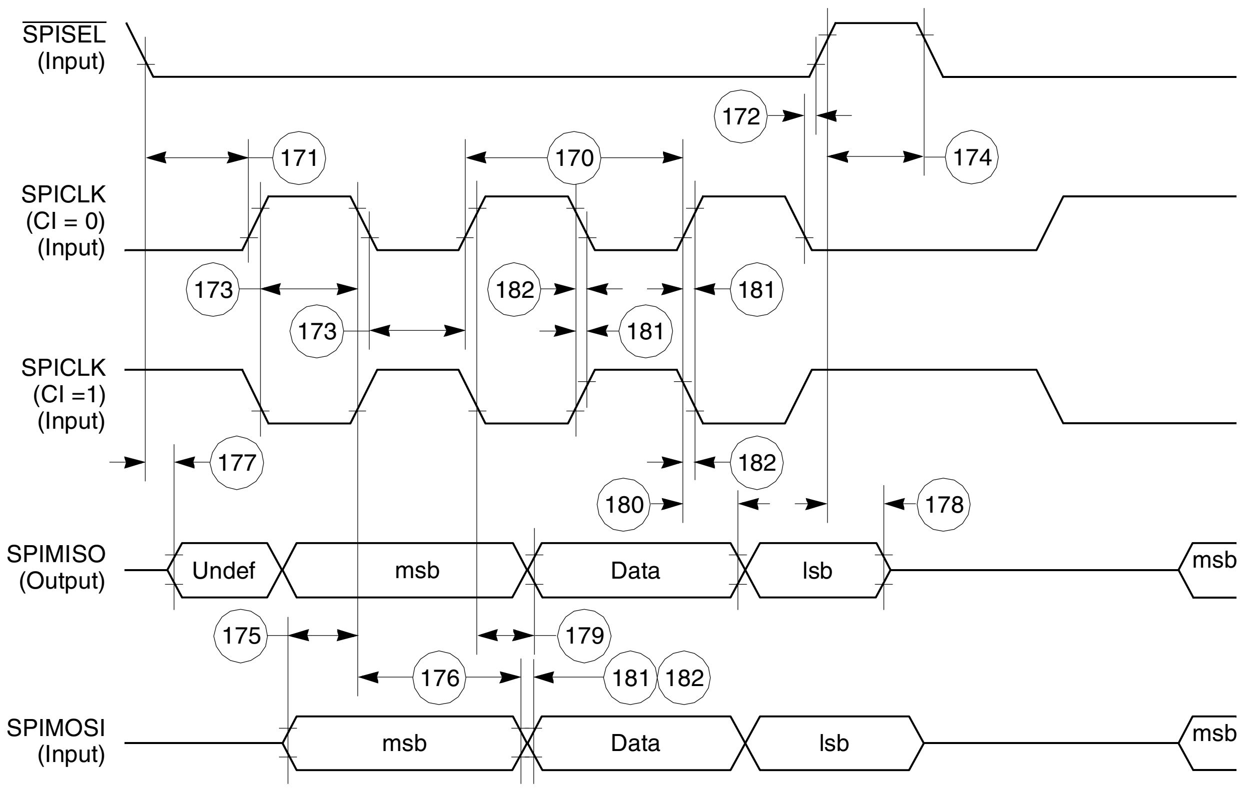


Figure 69. SPI Slave (CP = 1) Timing Diagram

12.12 I²C AC Electrical Specifications

Table 28 provides the I²C (SCL < 100 kHz) timings.

Table 28. I²C Timing (SCL < 100 kHz)

Num	Characteristic	All Frequencies		Unit
		Min	Max	
200	SCL clock frequency (slave)	0	100	kHz
200	SCL clock frequency (master)[1]	1.5	100	kHz
202	Bus free time between transmissions	4.7	—	µs
203	Low period of SCL	4.7	—	µs
204	High period of SCL	4.0	—	µs
205	Start condition setup time	4.7	—	µs
206	Start condition hold time	4.0	—	µs
207	Data hold time	0	—	µs
208	Data setup time	250	—	ns
209	SDL/SCL rise time	—	1	µs

Table 28. I²C Timing (SCL < 100 kHz) (continued)

Num	Characteristic	All Frequencies		Unit
		Min	Max	
210	SDL/SCL fall time	—	300	ns
211	Stop condition setup time	4.7	—	µs

1 SCL frequency is given by SCL = BRGCLK_frequency/((BRG register + 3) × pre_scaler × 2).
The ratio SyncClk/(BRGCLK/pre_scaler) must be greater or equal to 4/1.

Table 29 provides the I²C (SCL > 100 kHz) timings.

Table 29. I²C Timing (SCL > 100 kHz)

Num	Characteristic	Expression	All Frequencies		Unit
			Min	Max	
200	SCL clock frequency (slave)	fSCL	0	BRGCLK/48	Hz
200	SCL clock frequency (master)[1]	fSCL	BRGCLK/16512	BRGCLK/48	Hz
202	Bus free time between transmissions	—	1/(2.2 × fSCL)	—	s
203	Low period of SCL	—	1/(2.2 × fSCL)	—	s
204	High period of SCL	—	1/(2.2 × fSCL)	—	s
205	Start condition setup time	—	1/(2.2 × fSCL)	—	s
206	Start condition hold time	—	1/(2.2 × fSCL)	—	s
207	Data hold time	—	0	—	s
208	Data setup time	—	1/(40 × fSCL)	—	s
209	SDL/SCL rise time	—	—	1/(10 × fSCL)	s
210	SDL/SCL fall time	—	—	1/(33 × fSCL)	s
211	Stop condition setup time	—	1/2(2.2 × fSCL)	—	s

1 SCL frequency is given by SCL = BrgClk_frequency/((BRG register + 3) × pre_scaler × 2).
The ratio SyncClk/(Brg_Clk/pre_scaler) must be greater or equal to 4/1.

Figure 70 shows the I²C bus timing.

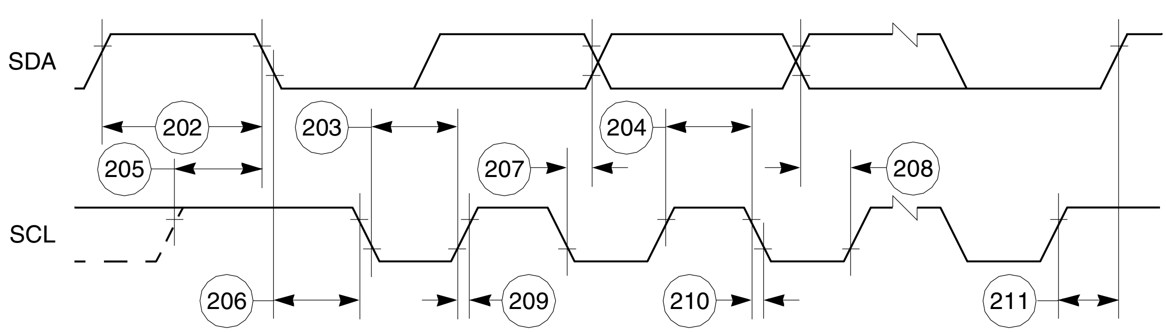


Figure 70. I²C Bus Timing Diagram

Figure 71 shows signal timings during UTOPIA receive operations.

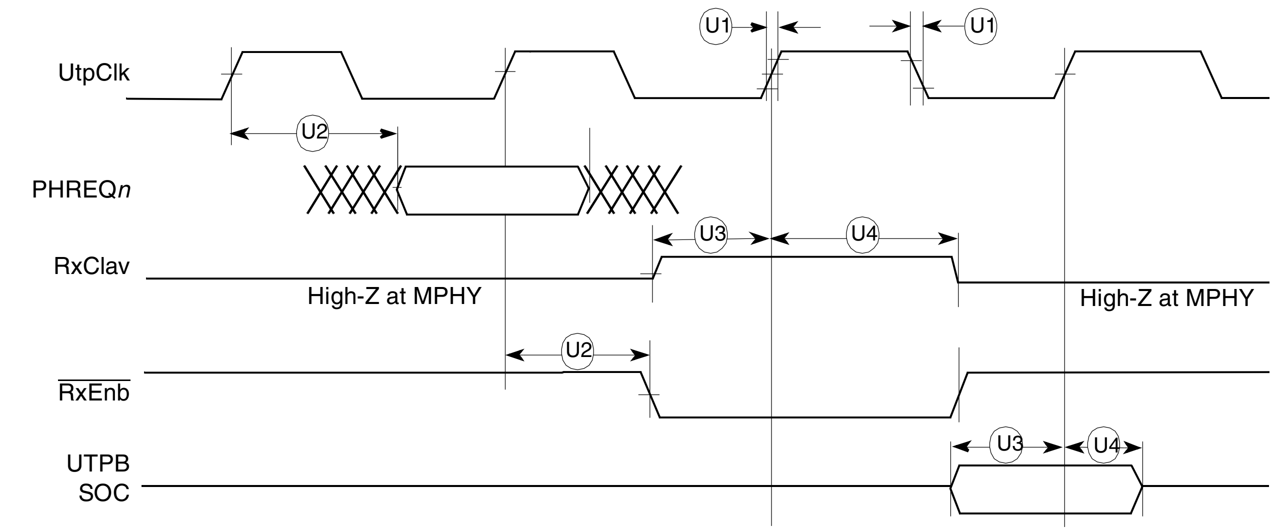


Figure 71. UTOPIA Receive Timing

Figure 72 shows signal timings during UTOPIA transmit operations.

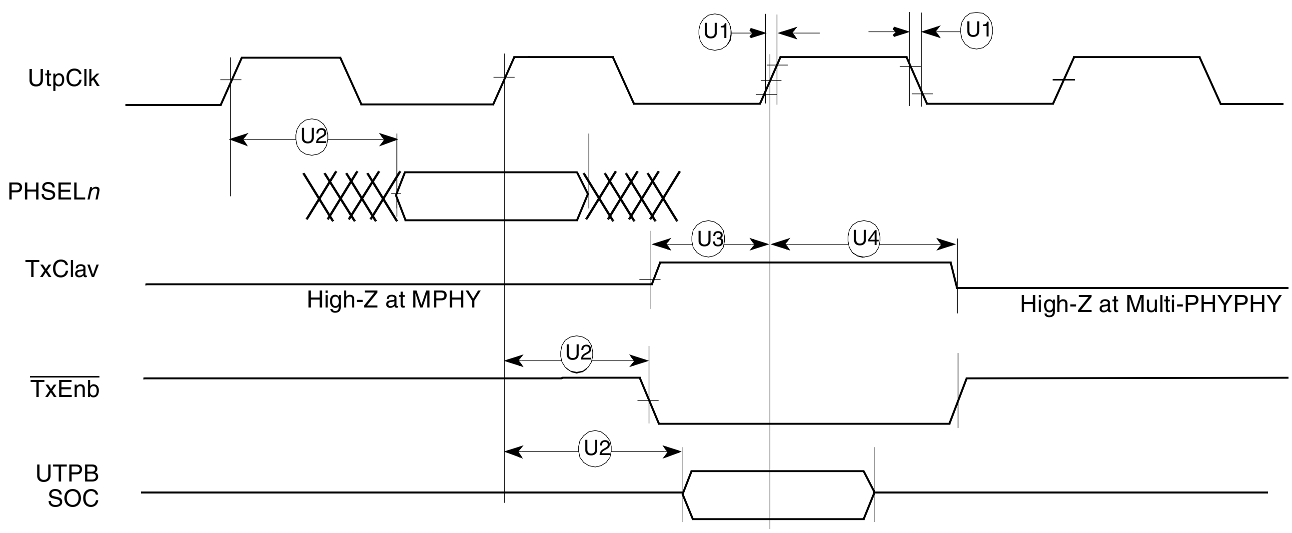


Figure 72. UTOPIA Transmit Timing

Table 39. Pin Assignments (continued)

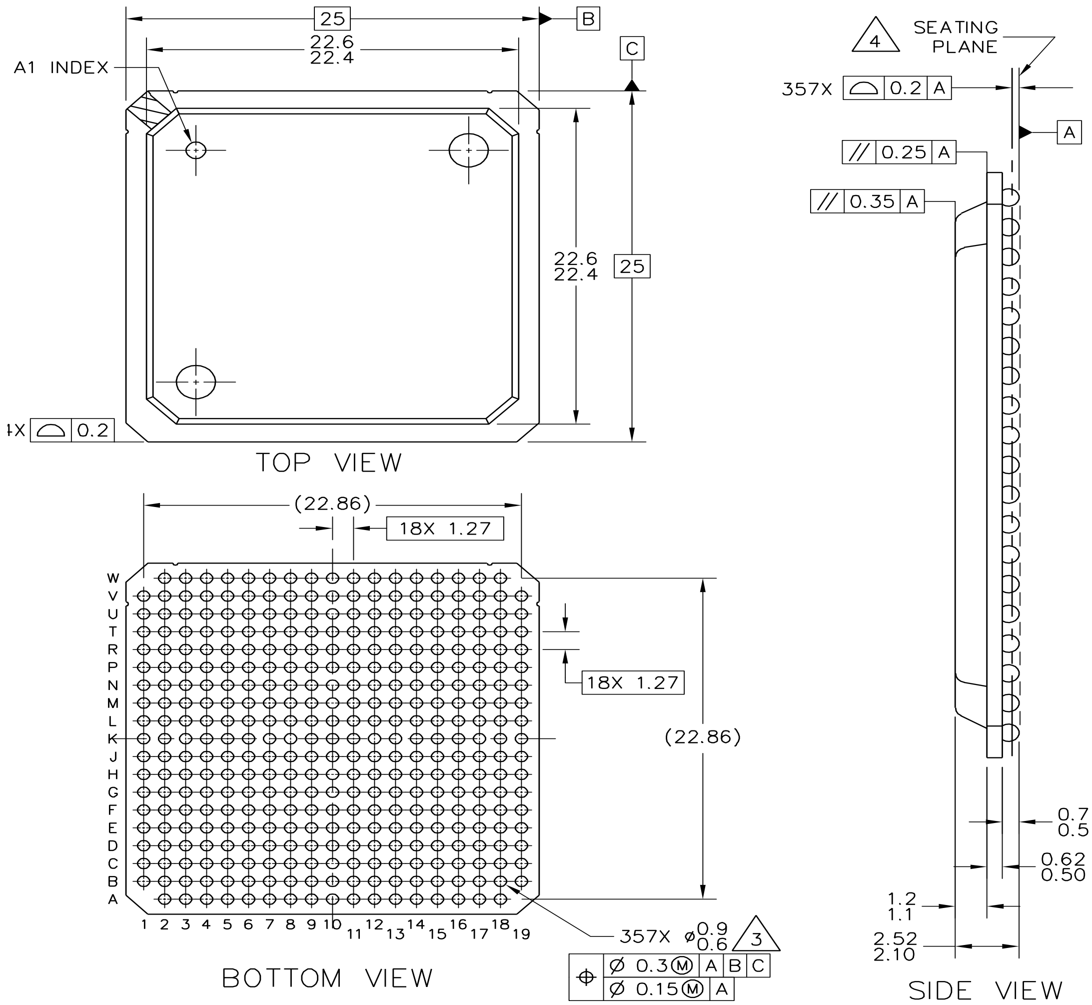
Name	Pin Number	Type
ALE_B, DSCK/AT1	D8	Bidirectional Three-state
IP_B[0:1], IWP[0:1], VFLS[0:1]	A9, D9	Bidirectional
IP_B2, IOIS16_B, AT2	C8	Bidirectional Three-state
IP_B3, IWP2, VF2	C9	Bidirectional
IP_B4, LWP0, VF0	B9	Bidirectional
IP_B5, LWP1, VF1	A10	Bidirectional
IP_B6, DSDI, AT0	A8	Bidirectional Three-state
IP_B7, PTR, AT3	B8	Bidirectional Three-state
OP0, UtpClk_Split[1]	B6	Bidirectional
OP1	C6	Output
OP2, MODCK1, STS	D6	Bidirectional
OP3, MODCK2, DSDO	A6	Bidirectional
BADDR30, REG	A7	Output
BADDR[28:29]	C5, B5	Output
AS	D7	Input
PA15, USBRXD	N16	Bidirectional
PA14, USBOE	P17	Bidirectional (Optional: open-drain)
PA13, RXD2	W11	Bidirectional
PA12, TXD2	P16	Bidirectional (Optional: open-drain)
PA11, RXD4, MII1-TXD0, RMII1-TXD0	W9	Bidirectional (Optional: open-drain)
PA10, MII1-TXER, TIN4, CLK7	W17	Bidirectional (Optional: open-drain)
PA9, L1TXDA, RXD3	T15	Bidirectional (Optional: open-drain)
PA8, L1RXDA, TXD3	W15	Bidirectional (Optional: open-drain)
PA7, CLK1, L1RCLKA, BRGO1, TIN1	V14	Bidirectional
PA6, CLK2, TOUT1	U13	Bidirectional
PA5, CLK3, L1TCLKA, BRGO2, TIN2	W13	Bidirectional

Table 39. Pin Assignments (continued)

Name	Pin Number	Type
PA4, $\overline{CTS4}$, MII1-TXD1, RMII1-TXD1	U4	Bidirectional
PA3, MII1-RXER, RMII1-RXER, BRGO3	W2	Bidirectional
PA2, MII1-RXDV, RMII1-CRS_DV, TXD4	T4	Bidirectional
PA1, MII1-RXD0, RMII1-RXD0, BRGO4	U1	Bidirectional
PA0, MII1-RXD1, RMII1-RXD1, $\overline{TOUT4}$	U3	Bidirectional
PB31, $\overline{SPISEL}$, MII1-TXCLK, RMII1-REFCLK	V3	Bidirectional (Optional: open-drain)
PB30, SPICLK	P18	Bidirectional (Optional: open-drain)
PB29, SPIMOSI	T19	Bidirectional (Optional: open-drain)
PB28, SPIMISO, BRGO4	V19	Bidirectional (Optional: open-drain)
PB27, I2CSDA, BRGO1	U19	Bidirectional (Optional: open-drain)
PB26, I2CSCL, BRGO2	R17	Bidirectional (Optional: open-drain)
PB25, RXADDR3[1], TXADDR3, SMTXD1	V17	Bidirectional (Optional: open-drain)
PB24, TXADDR3[1], RXADDR3, SMRXD1	U16	Bidirectional (Optional: open-drain)
PB23, TXADDR2[1], RXADDR2, $\overline{SDACK1}$, $\overline{SMSYN1}$	W16	Bidirectional (Optional: open-drain)
PB22, TXADDR4[1], RXADDR4, $\overline{SDACK2}$, $\overline{SMSYN2}$	V15	Bidirectional (Optional: open-drain)
PB21, SMTXD2, TXADDR1[1], BRG01, RXADDR1, PHSEL[1]	U14	Bidirectional (Optional: open-drain)
PB20, SMRXD2, L1CLKOA, TXADDR0[1], RXADDR0, PHSEL[0]	T13	Bidirectional (Optional: open-drain)
PB19, MII1-RXD3, $\overline{RTS4}$	V13	Bidirectional (Optional: open-drain)
PB18, RXADDR4[1], TXADDR4, $\overline{RTS2}$, L1ST2	T12	Bidirectional (Optional: open-drain)

16.2 Mechanical Dimensions of the PBGA Package

Figure 78 shows the mechanical dimensions of the PBGA package.



NOTES:

1. ALL DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M—1994.
3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
4. DATUM A, THE SEATING PLANE, IS DEFINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.

Figure 78. Mechanical Dimensions and Bottom Surface Nomenclature of the PBGA Package